

SR220 THRU SR2100

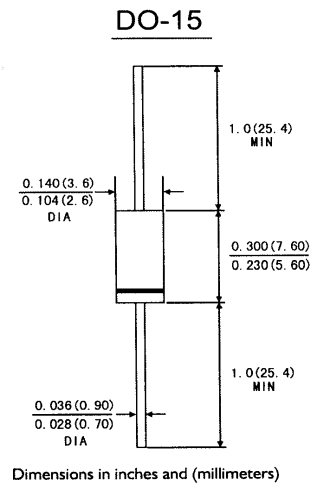
Schottky Barrier Rectifiers Reverse Voltage – 20 to 100 V Forward Current – 2.0 A

Features

- Guard ring for overvoltage protection
- Low power loss, high efficiency
- High current capability, low forward voltage drop
- High surge capability
- Metal silicon junction, majority carrier conduction

Mechanical Data

- **Case:** Molded plastic, DO-15.
- **Terminals:** Axial leads, solderable per MIL-STD-750, method 2026
- **Polarity:** Color band denotes cathode end
- **Mounting Position:** Any



Maximum Ratings and Characteristics

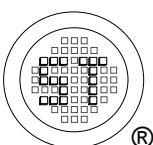
Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

Parameter	Symbols	SR 220	SR 230	SR 240	SR 250	SR 260	SR 280	SR 2100	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	20	30	40	50	60	80	100	V
Maximum RMS Voltage	V_{RMS}	14	21	28	35	42	57	71	V
Maximum DC Blocking Voltage	V_{DC}	20	30	40	50	60	80	100	V
Maximum Forward Voltage at 2 A ¹⁾	V_F	0.55		0.7		0.85			V
Maximum Average Forward Rectified Current 0.375"(9.5 mm) Lead Length at $T_L = 75\text{ }^\circ\text{C}$	$I_{(AV)}$	2							A
Peak Forward Surge Current 8.3 ms Single half sine-wave Superimposed on Rated Load (JEDEC Method)	I_{FSM}	50							A
Maximum Reverse Current at Rated DC Blocking Voltage ¹⁾	I_R			1					mA
				10					
Typical Junction Capacitance ³⁾	C_J	170							pF
Typical Thermal Resistance ²⁾	$R_{\theta JA}$	35							$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_j, T_{stg}	- 65 to + 125							$^\circ\text{C}$

¹⁾ Pulse test: 300 μs pulse width, 1% duty cycle

²⁾ Thermal resistance from junction to lead, and/or to ambient P.C.B mounted with 0.375"(9.5 mm) lead length with 1.5 X 1.5"(38 mm X 38 mm) copper pads

³⁾ Measure at 1 MHz and reverse voltage of 4 V.



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RATINGS AND CHARACTERISTIC CURVES SR220 THRU SR2100

FIG.1-FORWARD CURRENT DERATING CURVE

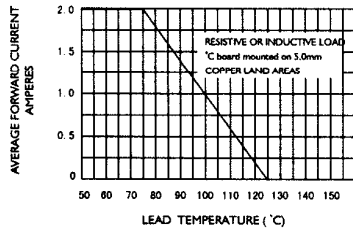


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

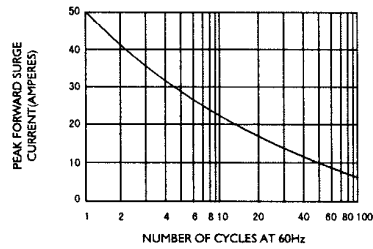


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

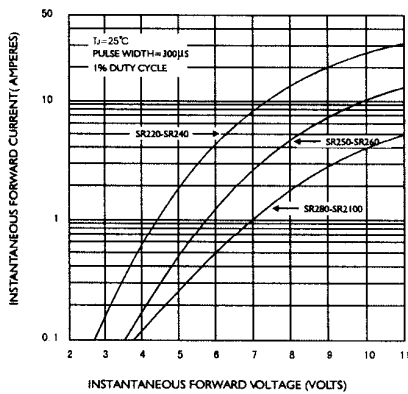


FIG.4-TYPICAL REVERSE CHARACTERISTICS

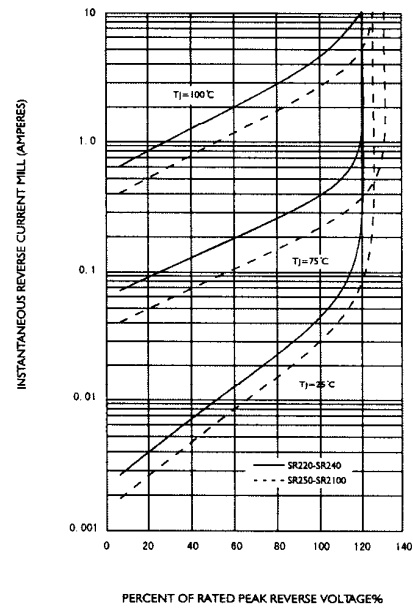
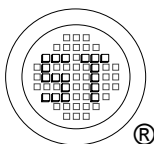
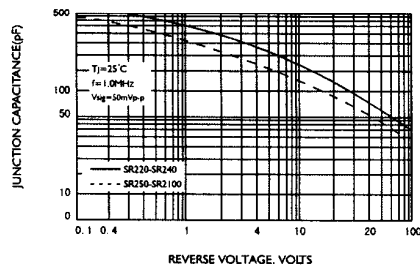


FIG.5-TYPICAL JUNCTION CAPACITANCE



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ISO/TS 16949 : 2009 Certificate No. 05103
 ISO 14001 : 2004 Certificate No. 7116
 ISO 9001 : 2008 Certificate No. 0506088
 BS-OHSAS 18001 : 2007 Certificate No. 7116
 IECQ QC 080000 Certificate No. PRC18P161851